# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

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## HOA088X/089X

**Transmissive Sensor** 

### FEATURES

- Phototransistor output
- Four mounting configurations
- Accurate position sensing
- 0.125 in.(3.18 mm) slot width
- Choice of detector aperture
- 24.0 in.(610 mm) min. 26 AWG UL 1429 wire leads
- Choice of opaque or IR transmissive housings

### DESCRIPTION

The HOA088X/089X series consists of an infrared emitting diode facing an NPN silicon phototransistor encased in a black thermoplastic housing. Phototransistor switching takes place whenever an opaque object passes through the slot between emitter and detector. This series allows the user to choose from available options: (1) mounting tab configuration, (2) detector aperture size, (3) electro-optical characteristics, and (4) housing materials.

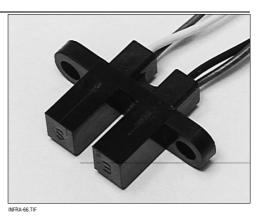
All devices employ a built-in strain relief for maximum wire attachment strength. The HOA088X series utilizes an IR transmissive polysulfone housing which features smooth optical faces without external aperture openings; this feature is desirable when aperture blockage from airborne contaminants is a possibility. The HOA089X series employs an opaque polysulfone housing with aperture openings for use in applications in which maximum rejection of ambient light is important and in situations where maximum position resolution is desired. The HOA088X/089X series employs plastic molded components. For additional component information see SEP8506 and SDP8406.

Housing material is polysulfone. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

The detector to emitter lead spacing is 0.32 in.(8.13 mm) for all versions. Wire color code and functions are:

Red - IRED Anode	White - Detector Collector
Black - IRED Cathode	Green - Detector Emitter

To specify the complete product characteristics, see PART NUMBER GUIDE.

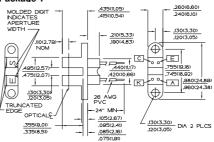


OUTLINE DIMENSIONS in inches (mm) Tolerance 3 plc decimals ±0.010(0.25)

:

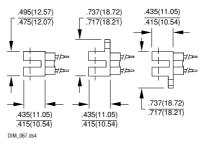
2 plc decimals  $\pm 0.020(0.51)$ 

#### Package T





PACKAGE N PACKAGE P PACKAGE L



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278

## HOA088X/089X

**Transmissive Sensor** 

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)								
PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS		
IR EMITTER								
Forward Voltage	VF			1.6	V	l <sub>F</sub> =20 mA		
Reverse Leakage Current	IR			10	μA	V <sub>R</sub> =3 V		
DETECTOR								
Collector-Emitter Breakdown Voltage	V(BR)CEO	30			V	Ic=100 μA		
Emitter-Collector Breakdown Voltage	V(BR)ECO	5.0			V	I <sub>E</sub> =100 μΑ		
Collector Dark Current	ICEO			100	nA	V <sub>CE</sub> =10 V, I <sub>F</sub> =0		
COUPLED CHARACTERISTICS								
On-State Collector Current	C(ON)				mA			
Parameter A		0.5				V <sub>CE</sub> =10, I <sub>F</sub> =20 mA		
(HOA0880/0890)								
Parameter B		1.0				Vce=5 V, IF=10 mA		
(HOA0881/0891)								
Parameter C		1.8				Vce=0.6, IF=20 mA		
(HOA0882/0892)								
Collector-Emitter Saturation Voltage	VCE(SAT)				V			
Parameter A				0.4		lc=0.4 mA, l⊧=20 mA		
(HOA0880/0890)								
Parameter B				0.4		lc=0.8 mA, I⊧=10 mA		
(HOA0881/0891)								
Parameter C				0.6		lc=1.8 mA, l⊧=20 mA		
(HOA0882/0892)								
Rise And Fall Time	t <sub>r</sub> , t <sub>f</sub>		15		μs	Vcc=5 V, lc=1 mA RL=1000 Ω		

### ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted) Operating Temperature Range -40°C to 85°C

Operating Temperature Range
Storage Temperature Range
Soldering Temperature (5 sec)
IR EMITTER
Power Dissipation
Reverse Voltage
Continuous Forward Current
DETECTOR
Collector-Emitter Voltage
Emitter-Collector Voltage
Power Dissipation
Collector DC Current

SCHEMATIC Anode Collector

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-40°C to 85°C 240°C

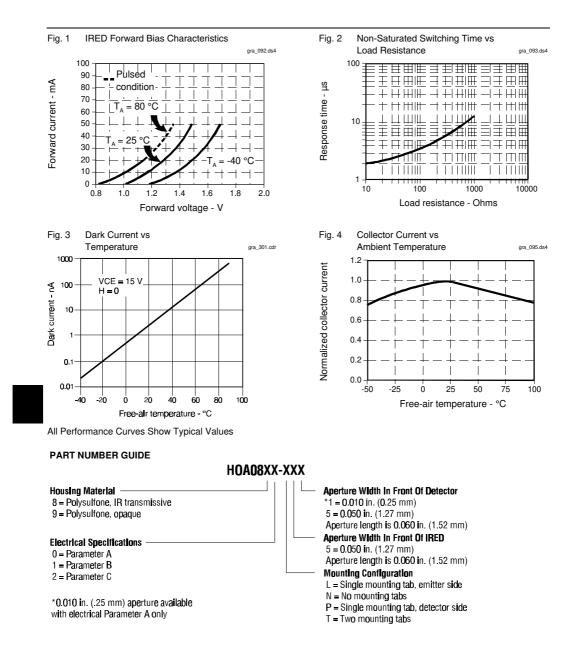
100 mW <sup>(1)</sup> 3 V 50 mA 30 V 5 V

100 mW (1)

30 mA

## HOA088X/089X

**Transmissive Sensor** 



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280



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